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# Power Matters<sup>™</sup>

Home ▶ 2N336 (#68289)

**Microsemi** 

#### 2N336 (#68289)

## Products

- ▶ Product Directory
- Applications Directory
- ▶ Parametric Search

### Overview Diagrams

DC Current Gain	HFE	25.00	275.00		00	
Maximum Electrical Rating		Symbol	Min	Тур	Max	Unit
Collector Current (dc)		I <sub>C</sub>			0.01	А
Collector-Emitter Voltage (Base	Open)	V <sub>CEO</sub>			45.00	V
		-			475.00	00

This part can be found in the following product categories:

- Non-Radiation Hardened Devices ► Transistors ► BJT( BiPolar Junction Transistor) ► NPN Transistor
- Discretes ▶ Transistors ▶ BJT( BiPolar Junction Transistor) ▶ NPN Transistor

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